

Positive Fixed 3.3V 0.3A Ultra-Low Dropout Voltage Regulator in bare die form

Rev 1.0 29/04/24

Description

The SiS293033 low-noise, low dropout, high precision linear regulator operates with up to 12V input and provides 300mA output current. Typical output noise is $44\mu V_{RMS}$ with dropout voltage 270mV at 150mA load. The SiS293033 is highly accurate over temperature and exhibits excellent load and line transient response. Ruggedized features include internal output current limiting; short-circuit protection and thermal overload protection. Very small die size enables high integration.

Features:

- Low Temperature Coefficient: ±100ppm/°C
- Low Dropout: 270mV at 150mA
- ± 3% Voltage Accuracy at 300mA load
- Excellent Line Regulation: 0.05%/V
- Low Noise (10Hz to 100kHz): 44µV_{RMS}
- High PSRR: 60dB Range to 10kHz
- Input Voltage up to 12V (absolute max 14V)
- Low Quiescent Current: 8µA.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Die Dimensions in μm (mils)



Mechanical Specification

| Die Size (Including Scribe) | 840 x 680 33.07 x 26.77 | µm mils | |
|-----------------------------|----------------------------|------------|--|
| Minimum Bond Pad Size | 70 x 70 2.75 x 2.75 | µm mils | |
| Die Thickness | 350 (±20) 13.78 (±0.79) | µm mils | |
| Top Metal Composition | Al 99.5% Cu 0.5%2µm | | |
| Back Metal Composition | Si | | |





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Pad Layout and Functions



Typical Application



* C1 Input capacitor is recommended for all applications

** C2 is recommended for stability. 1µF Tantalum capacitor or 6.8µF ceramic capacitor is recommended.





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Absolute Maximum Ratings¹

| PARAMETER | SYMBOL | VALUE | UNIT | |
|---|------------------|--------------------|------|--|
| Supply Voltage | V _{IN} | 14V | V | |
| Power Dissipation ² | PD | Internally Limited | | |
| Operating Junction Temperature ³ | TJ | -40 to 125 | °C | |
| Storage Temperature | T _{STG} | -65 to 150 | °C | |
| Thermal Resistance (Assembled in SOT-89-3) | R _{0JA} | 93.4 | °C/W | |
| ESD Capability(HBM) | V _{ESD} | 2 | kV | |

Recommended Operating Conditions

| PARAMETER | SYMBOL | MIN | MAX | UNIT |
|---|------------------|--------|-------|------|
| Input Voltage | V _{IN} | 4.3 | 12 | V |
| Output Current | I _{OUT} | 10 | 300 | mA |
| Operating Junction Temperature Range ³ | TJ | -40 te | o 125 | °C |

DC Electrical Characteristics C_{IN} C_{OUT} = 1µF, T_J = 25°C (unless noted otherwise)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|--------------------------------------|---|-------|------|-------|----------------------|
| Output Voltage | V _{OUT} | $V_{IN} = 4.3V$, $1mA \le I_{OUT} \le 10mA$ | 3.234 | 3.3 | 3.366 | V |
| Line Regulation ⁴ | ΔV_{OUT} | I_{OUT} = 10mA, 4V ≤ V_{IN} ≤6V | - | 0.05 | 0.2 | % / V _{OUT} |
| Load Regulation ⁴ | ΔV_{OUT} | V_{IN} = 4.3V, 1mA ≤ I_{OUT} ≤ 300mA | - | 60 | - | mV |
| Output Voltage Accuracy | | I _{OUT} = 300mA | -3 | - | +3 | % |
| Dropout Voltage | V _{DO} | I _{OUT} = 150mA | - | 270 | - | mV |
| Supply Current | Is | V_{IN} = 4.3V, V_{OUT} Floating | - | 8 | 15 | μA |
| Output Voltage Noise | V _n | BW = 10Hz~100kHz | - | 44 | - | μV _{RMS} |
| | $\Delta V_{OUT} / \Delta T. V_{OUT}$ | I _{OUT} = 10mA | - | ±100 | - | ppm/°C |
| Power Supply Rejection Ratio | PSRR | f = 100Hz Ripple = 0.5Vp-p, V _{IN} = 4.3V | - | 60 | - | dB |
| Maximum Output Current | I _{LIMIT} | V _{IN} - V _{OUT} = 1V | - | - | 340 | mA |
| Thermal Shutdown Threshold | T _{SHDN} | | - | 155 | - | °C |
| Thermal Shutdown Hysteresis | ΔT_{SHDN} | | - | 25 | - | °C |

1. Operation above absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. **2.** Maximum allowable power dissipation of any T_A (ambient temperature) is $P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature and the regulator will go into thermal shutdown **3.** This IC includes over temperature protection to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when over temperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability. **4.** Regulation is measured at a constant junction temperature, using pulse testing with a low duty cycle.





Typical Electrical Characteristics C_{IN} C_{OUT} = 1µF, T_J = 25°C (unless noted otherwise)





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